

## 100V NPN MEDIUM POWER TRANSISTOR IN TO252

#### **Features**

- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 3A Continuous Collector Current
- I<sub>CM</sub> = 5A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The MJD31CHQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

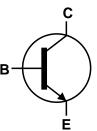
## **Mechanical Data**

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight: 0.34 grams (Approximate)

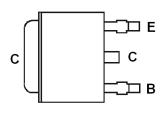




Top View



**Device Schematic** 



Pin Out Configuration Top View

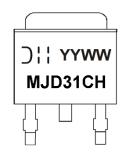
## Ordering Information (Note 4)

Part Number	Pookogo	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Fait Number	Package	Marking	Reel Size (Inches)	rape widin (min)	Qty.	Carrier
MJD31CHQ-13	TO252 (DPAK)	MJD31CH	13	16	2500	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



MJD31CH = Product Type Marking Code

OH = Manufacturers' Code Marking

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 24 = 2024)

WW = Week Code (01 to 53)



# **Absolute Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	Ic	3	A
Peak Pulse Collector Current	I <sub>CM</sub>	5	A
Continuous Base Current	lв	1	Α

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.60		
Power Dissipation	(Note 6)	P <sub>D</sub>	2.30	W	
	(Note 7)		1.45		
	(Note 5)		48		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	R <sub>0JA</sub> 54		°C/W
	(Note 7)		86		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

## ESD Ratings (Note 8)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

- 5. For a device mounted with the exposed collector pad on 25mm × 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
  6. Same as note (5), except mounted on 25mm × 25mm 1oz copper.
- 7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.

  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics**

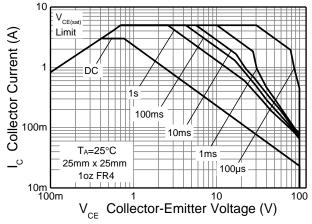


Figure 1. Safe Operating Area

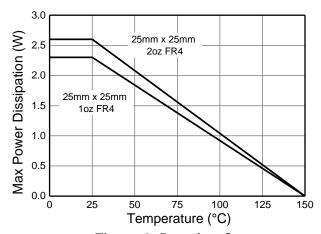
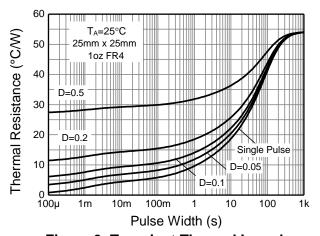
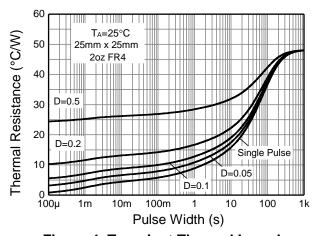


Figure 2. Derating Curve



**Figure 3. Transient Thermal Impedance** 



**Figure 4. Transient Thermal Impedance** 

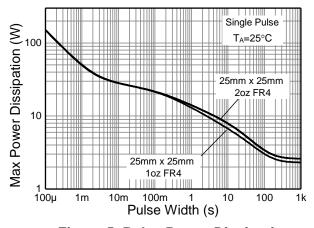


Figure 5. Pulse Power Dissipation



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	120	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	ВУЕВО	7	_	_	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	I <sub>CES</sub>	_	_	1	μΑ	V <sub>CE</sub> = 100V
Collector-Base Cut-Off Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 100V
Emitter Cut-Off Current	IEBO	_	_	1	μΑ	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	_	1.2	V	Ic = 3A, I <sub>B</sub> = 375mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	_	1.35	V	I <sub>C</sub> = 3A, I <sub>B</sub> = 375mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	_	1.8	V	Ic = 3A, VcE = 4V
		120	_	_		Vce = 60V, Ic = 20mA
DC Current Gain (Note 9)	hFE	100	_	_	_	$V_{CE} = 4V, I_{C} = 0.5A$
Do Garretti Gairi (Note 3)		25	_	_		$V_{CE} = 4V$ , $I_{C} = 1A$
		10	_	_		Vce = 4V, Ic = 3A
Small-Signal Current Gain	h <sub>fe</sub>	20	—	_	_	$V_{CE} = 10V$ , $I_{C} = 0.5A$ , $f = 1kHz$
Current Gain-Bandwidth Product	f <sub>T</sub>	3	_	_	MHz	$V_{CE} = 10V$ , $I_{C} = 0.5A$ , $f = 100MHz$
Output Capacitance	Cobo	_	15	_	pF	V <sub>CB</sub> = 10V, f = 1MHz
Input Capacitance	Cibo	_	310	_	pF	V <sub>EB</sub> = 0.5V, f = 1MHz
Delay Time	t <sub>d</sub>	_	30	_	ns	
Rise Time	tr	_	20	_	ns	Ic = 0.5A, Vcc = 10V,
Storage Time	ts		430	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Fall Time	t <sub>f</sub>	_	80	_	ns	

Note:

9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s.$  Duty cycle  $\leq 2\%.$ 



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

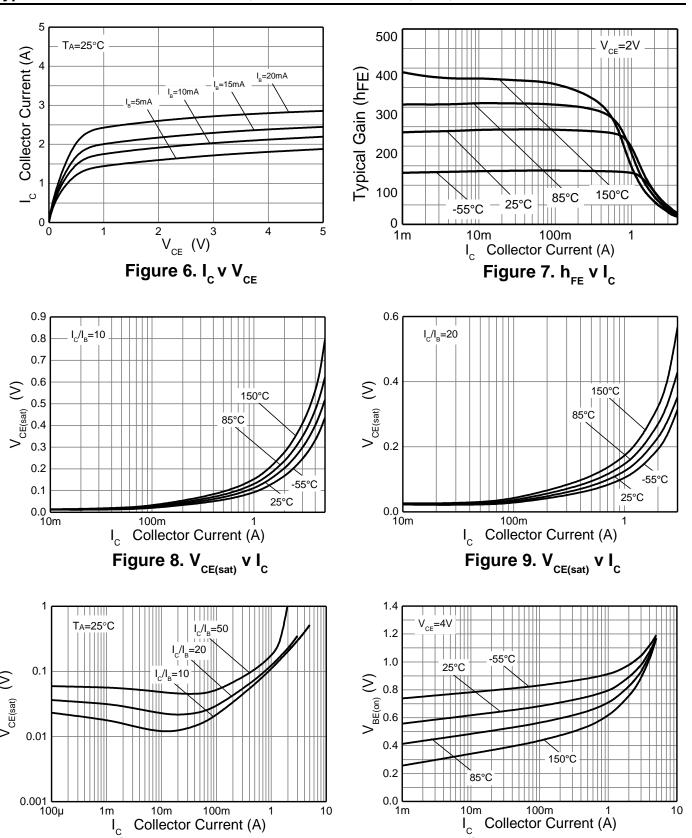


Figure 10. V<sub>CE(sat)</sub> v I<sub>C</sub>

Figure 11. V<sub>BE(on)</sub> v I<sub>C</sub>



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.) (continued)

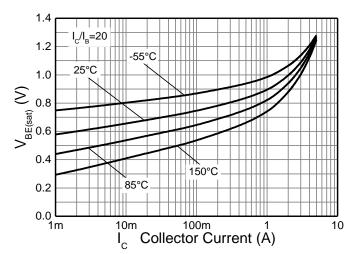


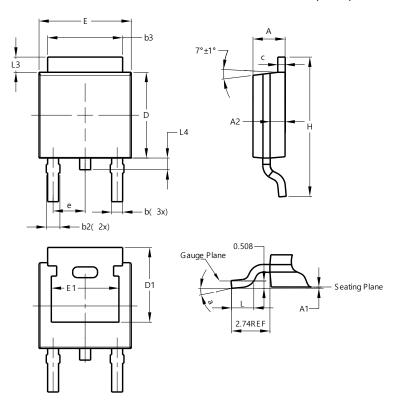
Figure 12.  $V_{\rm BE(sat)}$  v  $I_{\rm c}$ 



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## TO252 (DPAK)

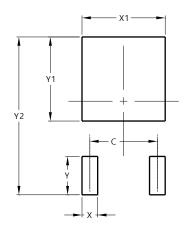


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A</b> 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.	286 BS	S		
Е	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		



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